

Hitachi High-Tech

HITACHI

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HitachiHigh-TechsuesFElJapanforPatentInfring ement

On August 19 2011, Hitachi High-Technologies Corpor ation (TOKYO:8036, Hitachi High-Tech) filed a lawsuit against FEI Japan at the Tokyo District Court, claiming damages for infringement of Japanese Patent No. 2,7 74,884* related to the Micro-Sampling technology using Focused Ion Beam, t aking the effective period of the samepatentintoconsideration.

Hitachi High-Technologies considers its intellectua I property rights as extremely important management resources, and will make every effort to protect such rights.

[Note]

Japanese Patent No. 2,774,884: On August 12 20 11, Intelletual Property High Court 5, 2011, Tokyo District Court dissmissed the appeal filed by FEI Japan. On June 1 madeapreliminaryinjunctionorderagainstFEIJap antostopmanufacture, sale and import of Quanta 3DFEG(Equippedwithaprobe(OmniprobeorAutoprobe)and GISapparatus with Platinum Deposition gas, Tungsten Deposition gas, or Carbon Deposition gas). FEI Japan filed an objection to this premilinary injunction o rder and has filed an appeal before the Intellectual Property High Court. Intellectual Property Hight Court accepted the preliminaryinjunctionorderagainstFEIJapanand dismissedFEIJapan'sappeal. *GISapparatus:GasInjectionSystem

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